

Photo interrupter, double-layer mold type

RPI-124

The RPI-124 is an ultra-small size, double-layer mold photointerrupter.

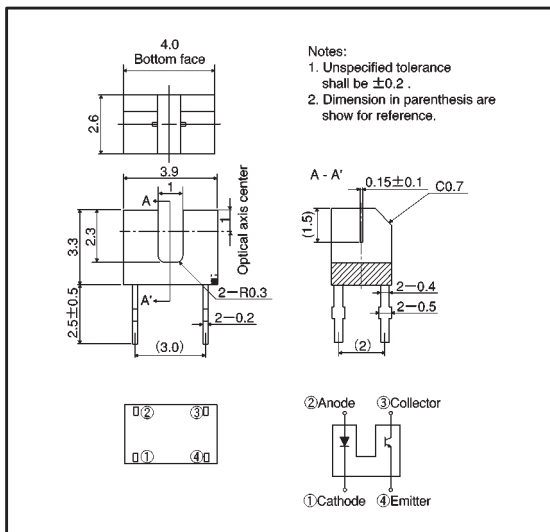
● External dimensions (Units: mm)

● Applications

Optical control equipment
Cameras
Floppy disk drives

● Features

- 1) Ultra-small.
- 2) High-precision position detection (slit width = 0.15 mm).
- 3) Minimal influence from stray light.
- 4) Low collector-emitter saturation voltage.



● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	I _F	50	mA
	Reverse voltage	V _R	5	V
	Power dissipation	P _D	80	mW
Output (photo-transistor)	Collector-emitter voltage	V _{CEO}	30	V
	Emitter-collector voltage	V _{ECO}	4.5	V
	Collector current	I _C	30	mA
	Collector power dissipation	P _C	80	mW
Operating temperature		T _{opr}	-25~+85	°C
Storage temperature		T _{stg}	-30~+100	°C

● Electrical and optical characteristics (Ta = 25°C)

	Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input characteristics	Forward voltage	V_F	—	1.3	1.6	V	$I_F=50\text{mA}$
	Reverse current	I_R	—	—	10	μA	$V_R=5\text{V}$
	Dark current	I_{CEO}	—	—	0.5	μA	$V_{CE}=10\text{V}$
Output characteristics	Peak sensitivity wavelength	λ_P	—	800	—	nm	—
Transfer characteristics	Collector current	I_C	0.3	—	1.5	mA	$V_{CC}=5\text{V}$, $I_F=20\text{mA}$
	Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.3	V	$I_F=20\text{mA}$, $I_C=0.15\text{mA}$
	Response time	$t_r \cdot t_f$	—	10	—	μs	$V_{CC}=5\text{V}$, $I_F=20\text{mA}$, $R_L=100\Omega$

● Electrical and optical characteristic curves

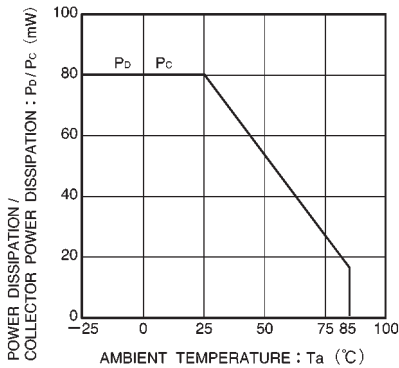


Fig.1 Power dissipation / collector power dissipation vs. ambient temperature

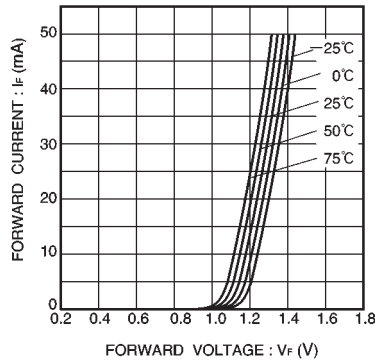


Fig.2 Forward current vs. forward voltage

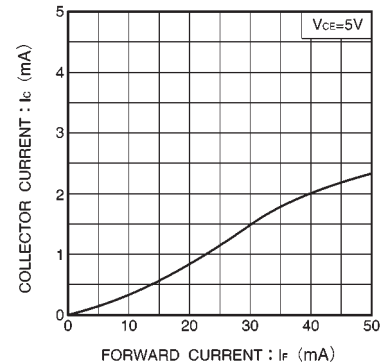


Fig.3 Collector current vs. forward current

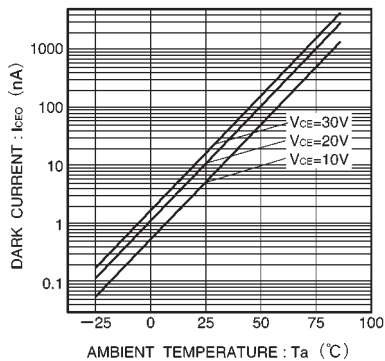


Fig.4 Dark current vs. ambient temperature

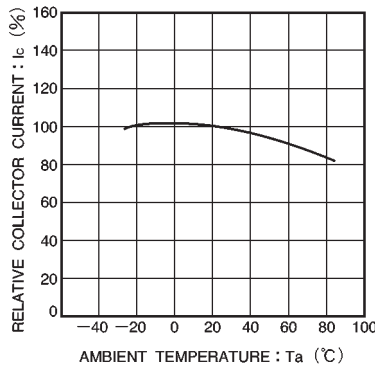


Fig.5 Relative output vs. ambient temperature

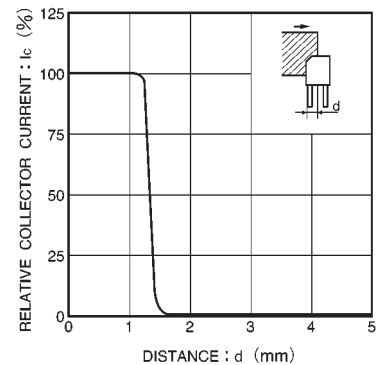


Fig.6 Relative output current vs. distance (I)

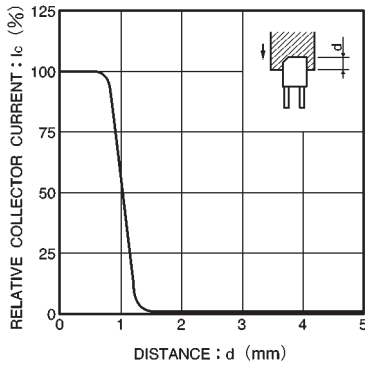


Fig.7 Relative output current vs. distance (II)

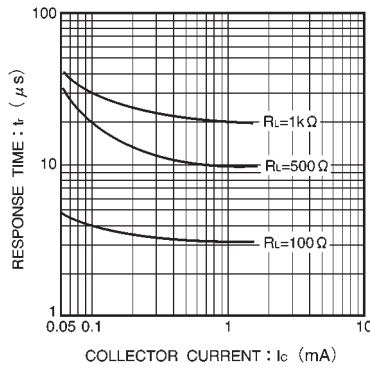


Fig.8 Response time vs. collector current

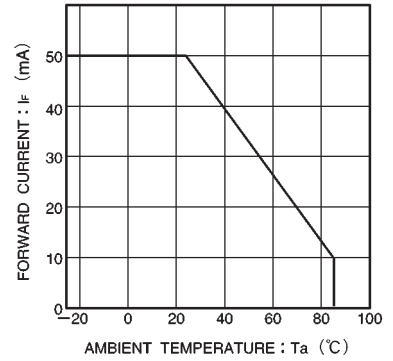


Fig.9 Forward current falloff

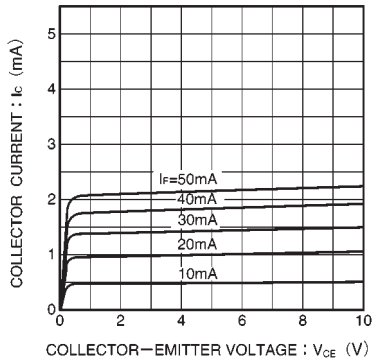
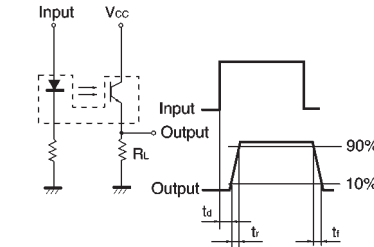


Fig.10 Output characteristics



t_d : Delay time
 t_r : Rise time (time for output current to rise from 10% to 90% of peak current)
 t_f : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time measurement circuit